NSN 5961-01-119-9053



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-119-9053 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-5 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.020 inches **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 85.0 collector to emitter voltage, dc with specified circuit between base and emitter and 60.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 25.0 degrees celsius ambient air and 25.0 degrees celsius case and 200.0 degrees celsius junction **Special Features:** Weapon system essential; junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life:

No

Unit Of Measure:

Demilitarization:

N/a

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